NSN 5961-00-783-7496

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-783-7496 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.230 inches **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 45.0 collector to base voltage/static/emitter open all transistor and 45.0 collector-to-emitter, substaining voltage, base open-circuited all transistor and 6.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 100.00 microamperes source cutoff current all transistor **Power Rating Per Characteristic:** 0.3 watts small-signal input power, common-collector all transistor **Transfer Ratio:** 3.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0